

DERWENT- 1992-057503
ACC-NO:

DERWENT- 199208
WEEK:

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TITLE: Semiconductor etching bath - comprises potassium hydroxide and potassium bromate or iodate NoAbstract

PATENT-ASSIGNEE: TESLA ROZNOV A/S[TESL]

PRIORITY-DATA: 1989CS-0006929 (December 7, 1989)

PATENT-FAMILY:

PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
CS 8906929 A	December 17, 1991	N/A	000	N/A

APPLICATION-DATA:

PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
CS 8906929A	N/A	1989CS-0006929	December 7, 1989

INT-CL C03C015/00, C09K013/02 , C23F001/32 , C30B033/10 ,
(IPC): H01L021/30

ABSTRACTED-PUB-NO:

EQUIVALENT-ABSTRACTS:

TITLE- SEMICONDUCTOR ETCH BATH COMPRISE POTASSIUM HYDROXIDE
TERMS: POTASSIUM BROMATE IODATE NOABSTRACT

DERWENT-CLASS: L03 M14

SECONDARY-ACC-NO:

CPI Secondary Accession Numbers: C1992-025948